

# High voltage discharge, High speed switching, Low Noise (–60V, –3A)

## 2SA2073

### ●Features

- 1) High speed switching. (  $t_f$  : Typ. : 20ns at  $I_c = -3A$  )
- 2) Low saturation voltage, typically.  
(Typ. : –200mV at  $I_c = -2.0A$ ,  $I_B = -200mA$  )
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Low Noise.
- 5) Complements the 2SC5826.

### ●Applications

High speed switching, Low noise

### ●Structure

PNP silicon epitaxial planar transistor

### ●Packaging specifications

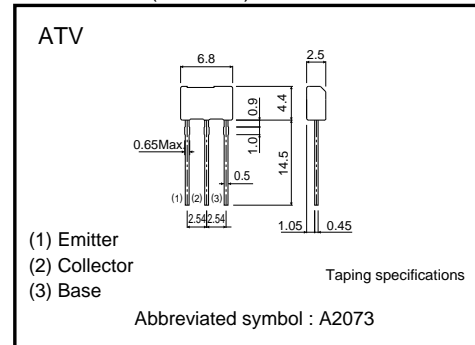
Type	Package	Taping
	Code	TV2
	Basic ordering unit (pieces)	2500
2SA2073		○

### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Collector-base voltage	$V_{CB0}$	–60	V	
Collector-emitter voltage	$V_{CE0}$	–60	V	
Emitter-base voltage	$V_{EB0}$	–6	V	
Collector current	DC	$I_c$	–3	A
	Pulsed	$I_{CP}$	–6	A *
Power dissipation	$P_c$	1.0	W	
Junction temperature	$T_j$	150	°C	
Range of storage temperature	$T_{stg}$	–55 to 150	°C	

\*Pw=10ms

### ●Dimensions (Unit : mm)



## Transistors

## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	-60	-	-	V	I <sub>C</sub> =-1mA
Collector-base breakdown voltage	BV <sub>CBO</sub>	-60	-	-	V	I <sub>C</sub> =-100μA
Emitter-base breakdown voltage	BV <sub>EBO</sub>	-6	-	-	V	I <sub>E</sub> =-100μA
Collector cut-off current	I <sub>CBO</sub>	-	-	-1.0	μA	V <sub>CB</sub> =-40V
Emitter cut-off current	I <sub>EBO</sub>	-	-	-1.0	μA	V <sub>EB</sub> =-4V
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	-	-200	-500	mV	I <sub>C</sub> =-2.0A I <sub>B</sub> =-200mA
DC current gain	h <sub>FE</sub>	120	-	270	-	V <sub>CE</sub> =-2V I <sub>C</sub> =-100mA
Transistor frequency	f <sub>T</sub>	-	200	-	MHz	V <sub>CE</sub> =-10V I <sub>E</sub> =100mA f=10MHz
Collector output capacitance	C <sub>ob</sub>	-	40	-	pF	V <sub>CB</sub> =-10V I <sub>E</sub> =0mA f=1MHz
Turn-on time	t <sub>on</sub>	-	20	-	ns	I <sub>C</sub> =-3A
Storage time	t <sub>stg</sub>	-	130	-	ns	I <sub>B1</sub> =-300mA I <sub>B2</sub> =300mA
Fall time	t <sub>f</sub>	-	20	-	ns	V <sub>CC</sub> =-25V

\*1 Single pulse

\*2 See switching characteristics measurement circuits

●h<sub>FE</sub> RANK

Q
120-270

Transistors

●Electrical characteristics curves

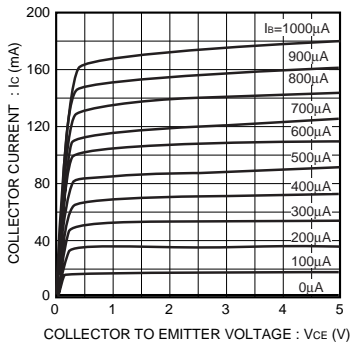


Fig.1 Typical output characteristics

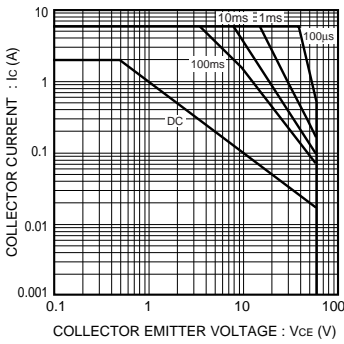


Fig.2 Safe operating area

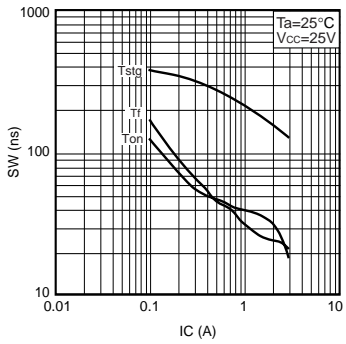


Fig.3 Switching Time

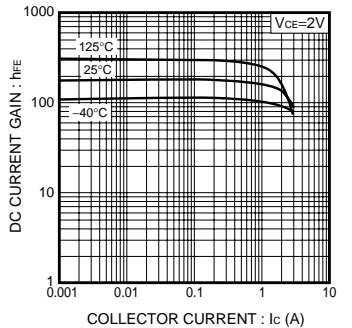


Fig.4 DC current gain vs. collector current ( I )

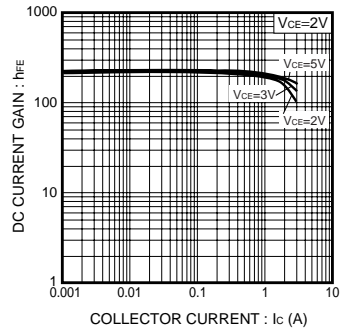


Fig.5 DC current gain vs. collector current ( II )

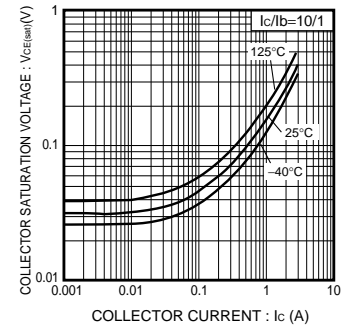


Fig.6 Collector-emitter saturation voltage vs. collector current ( I )

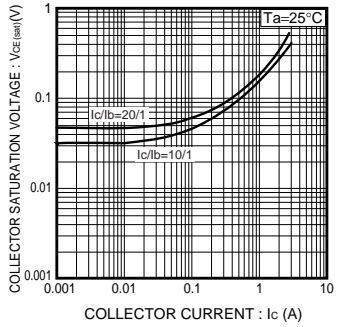


Fig.7 Collector-emitter saturation voltage vs. collector current ( II )

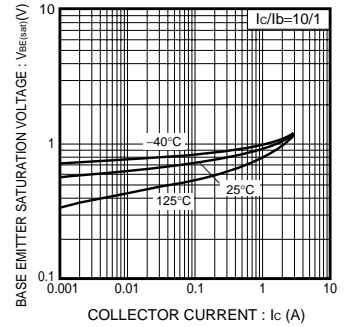


Fig.8 Base-emitter saturation voltage vs. collector current

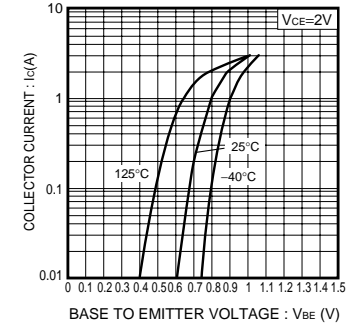


Fig.9 Grounded emitter propagation characteristics

Transistors

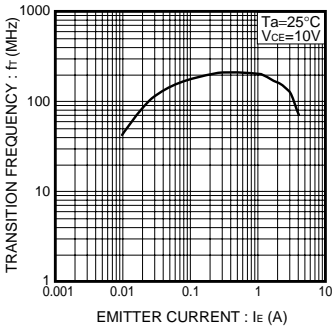


Fig.10 Transition frequency

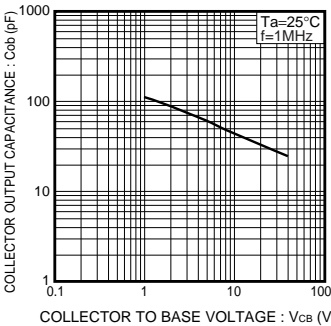
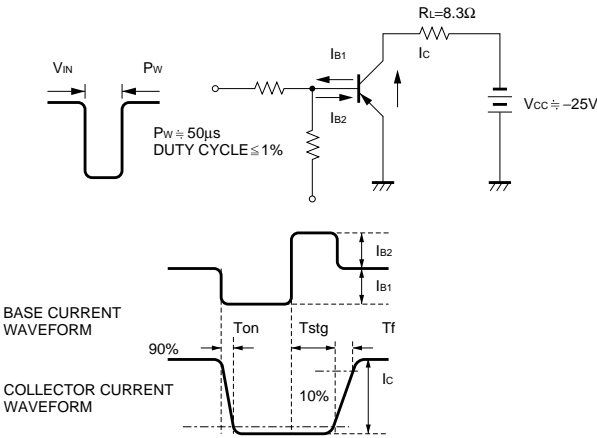


Fig.11 Collector output capacitance

●Switching characteristics measurement circuits



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